NSS1C200MZ4, NSV1C200MZ4 100 V, 2.0 A, Low V_{CE(sat)} **PNP Transistor**

ON Semiconductor's e²PowerEdge family of low V_{CE(sat)} transistors are miniature surface mount devices featuring ultra low saturation voltage (V_{CE(sat)}) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e²PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V _{CEO}	-100	Vdc
Collector-Base Voltage	V _{CBO}	-140	Vdc
Emitter-Base Voltage	V _{EBO}	-7.0	Vdc
Base Current – Continuous	Ι _Β	1.0	Α
Collector Current – Continuous	Ι _C	2.0	А
Collector Current – Peak	I _{CM}	3.0	А

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D (Note 1)	800 6.5	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 1)	155	°C/W
Total Device Dissipation T _A = 25°C Derate above 25°C	P _D (Note 2)	2.0 15.6	W mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$ (Note 2)	64	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	–55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

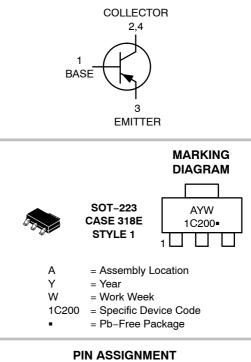
1. FR-4 @ 7.6 mm², 1 oz. copper traces. 2. FR-4 @ 645 mm², 1 oz. copper traces.

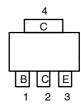


ON Semiconductor®

http://onsemi.com

-100 VOLTS, 2.0 AMPS PNP LOW V_{CE(sat)} TRANSISTOR





Top View Pinout

ORDERING INFORMATION

Device	Package	Shipping [†]
NSS1C200MZ4T1G NSV1C200MZ4T1G	SOT-223 (Pb-Free)	1000/ Tape & Reel
NSS1C200MZ4T3G	SOT-223 (Pb-Free)	4000/ Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

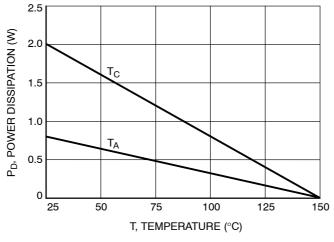
NSS1C200MZ4, NSV1C200MZ4

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage ($I_C = -10 \text{ mAdc}, I_B = 0$)	V _{(BR)CEO}	-100			Vdc
Collector – Base Breakdown Voltage ($I_C = -0.1 \text{ mAdc}, I_E = 0$)	V _{(BR)CBO}	-140			Vdc
Emitter – Base Breakdown Voltage ($I_E = -0.1 \text{ mAdc}, I_C = 0$)	V _{(BR)EBO}	-7.0			Vdc
Collector Cutoff Current (V _{CB} = -140 Vdc, I _E = 0)	I _{CBO}			-100	nAdc
Emitter Cutoff Current (V _{EB} = -6.0 Vdc)	I _{EBO}			-50	nAdc
ON CHARACTERISTICS					
DC Current Gain (Note 3)	h _{FE}				

DC Current Gain (Note 3) $(I_C = -10 \text{ mA}, V_{CE} = -2.0 \text{ V})$ $(I_C = -500 \text{ mA}, V_{CE} = -2.0 \text{ V})$ $(I_C = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V})$ $(I_C = -2.0 \text{ A}, V_{CE} = -2.0 \text{ V})$	hFE	150 120 80 50		360	
Collector – Emitter Saturation Voltage (Note 3) ($I_C = -0.1 \text{ A}, I_B = -0.010 \text{ A}$) ($I_C = -0.5 \text{ A}, I_B = -0.050 \text{ A}$) ($I_C = -1.0 \text{ A}, I_B = -0.100 \text{ A}$) ($I_C = -2.0 \text{ A}, I_B = -0.200 \text{ A}$)	V _{CE(sat)}			-0.040 -0.080 -0.125 -0.220	V
Base – Emitter Saturation Voltage (Note 3) $(I_C = -1.0 \text{ A}, I_B = -0.100 \text{ A})$	V _{BE(sat)}			-0.950	V
Base – Emitter Turn–on Voltage (Note 3) $(I_C = -1.0 \text{ A}, V_{CE} = -2.0 \text{ V})$	V _{BE(on)}			-0.850	V
Cutoff Frequency (I _C = -100 mA, V _{CE} = -5.0 V, f = 100 MHz)	f _T		120		MHz
Input Capacitance (V _{EB} = 3.0 V, f = 1.0 MHz)	Cibo		200		pF
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	Cobo		22		pF

3. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle \leq 2%.

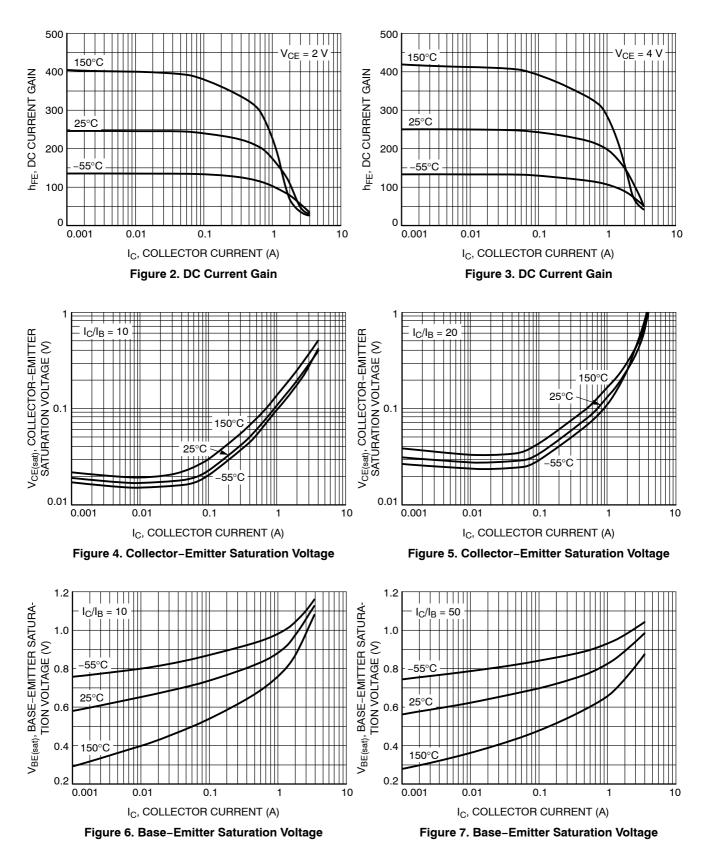


TYPICAL CHARACTERISTICS

Figure 1. Power Derating

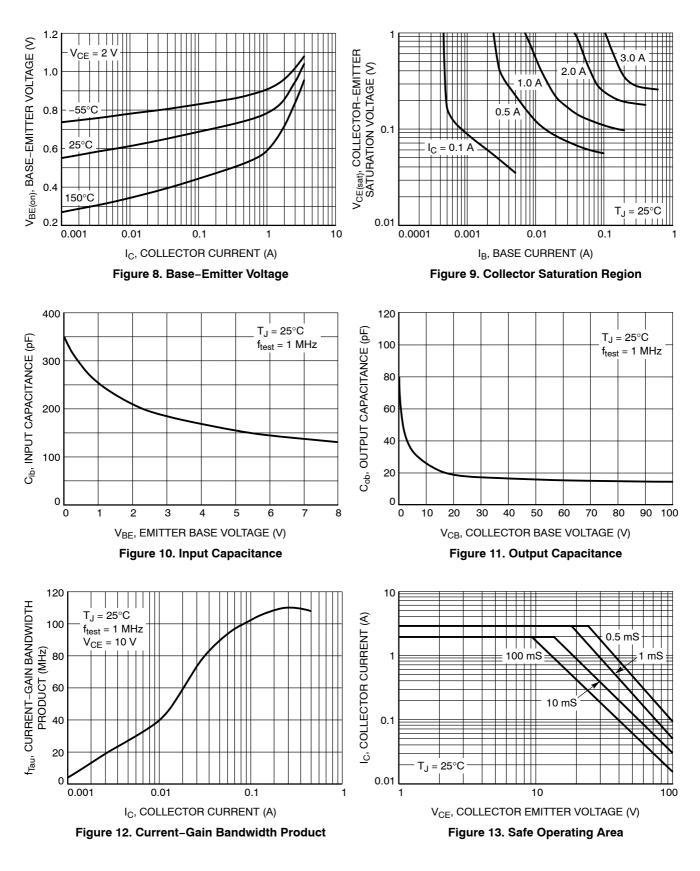
NSS1C200MZ4, NSV1C200MZ4

TYPICAL CHARACTERISTICS



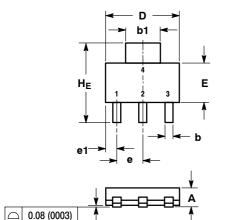
NSS1C200MZ4, NSV1C200MZ4

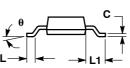
TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SOT-223 (TO-261) CASE 318E-04 **ISSUE N**





 2. CONTROLLING DIMENSION: INCH. 							
	MILLIMETERS		INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.50	1.63	1.75	0.060	0.064	0.068	
A1	0.02	0.06	0.10	0.001	0.002	0.004	
b	0.60	0.75	0.89	0.024	0.030	0.035	
b1	2.90	3.06	3.20	0.115	0.121	0.126	
с	0.24	0.29	0.35	0.009	0.012	0.014	
D	6.30	6.50	6.70	0.249	0.256	0.263	
Е	3.30	3.50	3.70	0.130	0.138	0.145	
е	2.20	2.30	2.40	0.087	0.091	0.094	
e1	0.85	0.94	1.05	0.033	0.037	0.041	
L	0.20			0.008			

2.00

7.30

10

0.069

0.276

0.060

0.264

0

0.078

0.287

10

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MICH.

STYLE 1 PIN 1. BASE 2. COLLECTOR 3. EMITTER 4 COLLECTOR

1.50

6.70

0

1.75

7.00

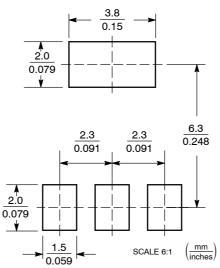
NOTES

L1

HE

θ

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typical" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor: NSV1C200MZ4T1G